


SPECIFICATIONS

Customer	
Product Name	Dual Series Schottky Barrier Diodes
Oyd Part	BAT54C
Package	SOT-23

Approved By	Checked By	Issued By
_____	_____	

Shenzhen Ouyada Electronics Co., Ltd.

Address: Galaxy Century Building located at the southwest junction of Shennan Avenue and Caitian Road, Futian District, Shenzhen Room 2412-2413 A building

Tel: 0086-755-82793361 83951116 Fax: 0086-755-83951115 E-Mail:oyd@szoyd.com

【For Customer approval Only】

Date: _____

Qualification Status: Full Restricted Rejected

Approved By	Verified By	Re-checked By	Checked By

Comments:

Dual Series Schottky Barrier Diodes

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

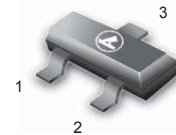
- Extremely Fast Switching Speed
- Low Forward Voltage — 0.35 Volts (Typ) @ $I_F = 10$ mAdc

ORDERING INFORMATION

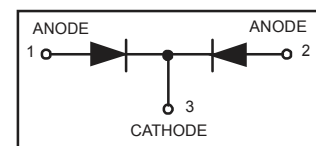
Device	Package	Shipping
BAT54C	SOT-23	3000/Tape & Reel

Preferred: devices are recommended choices for future use and best overall value.

BAT54C



SOT-23

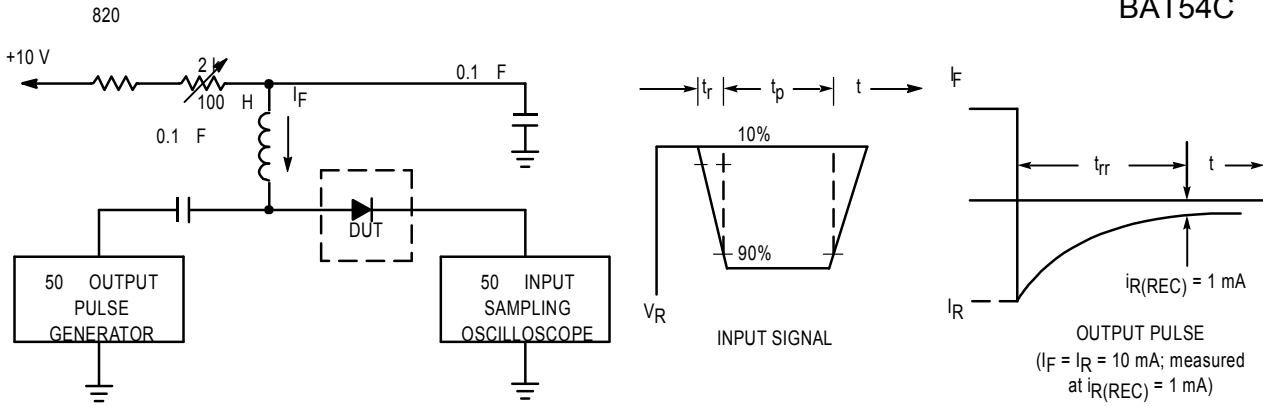


MAXIMUM RATINGS ($T_J = 125^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	V_R	30	Volts
Forward Power Dissipation @ $T_A = 25^\circ\text{C}$	P_F	225	mW
Derate above 25°C		1.8	mW/ $^\circ\text{C}$
Forward Current(DC)	I_F	200Max	mA
Junction Temperature	T_J	125Max	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
Reverse Breakdown Voltage ($I_R = 10$ A)	$V_{(BR)R}$	30	—	—	Volts
Total Capacitance ($V_R = 1.0$ V, $f = 1.0$ MHz)	C_T	—	7.6	10	pF
Reverse Leakage ($V_R = 25$ V)	I_R	—	0.5	2.0	Adc
Forward Voltage ($I_F = 0.1$ mAdc)	V_F	—	0.22	0.24	Vdc
Forward Voltage ($I_F = 30$ mAdc)	V_F	—	0.41	0.5	Vdc
Forward Voltage ($I_F = 100$ mAdc)	V_F	—	0.52	0.8	Vdc
Reverse Recovery Time ($I_F = I_R = 10$ mAdc, $I_{R(REC)} = 1.0$ mAdc, Figure 1)	t_{rr}	—	—	5.0	ns
Forward Voltage ($I_F = 1.0$ mAdc)	V_F	—	0.29	0.32	Vdc
Forward Voltage ($I_F = 10$ mAdc)	V_F	—	0.35	0.40	Vdc
Forward Current (DC)	I_F	—	—	200	mAdc
Repetitive Peak Forward Current	I_{FRM}	—	—	300	mAdc
Non-Repetitive Peak Forward Current ($t < 1.0$ s)	I_{FSM}	—	—	600	mAdc



- Notes: 1. A 2.0 k variable resistor adjusted for a Forward Current (I_F) of 10 mA.
 2. Input pulse is adjusted so $I_{R(\text{peak})}$ is equal to 10 mA.
 3. $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

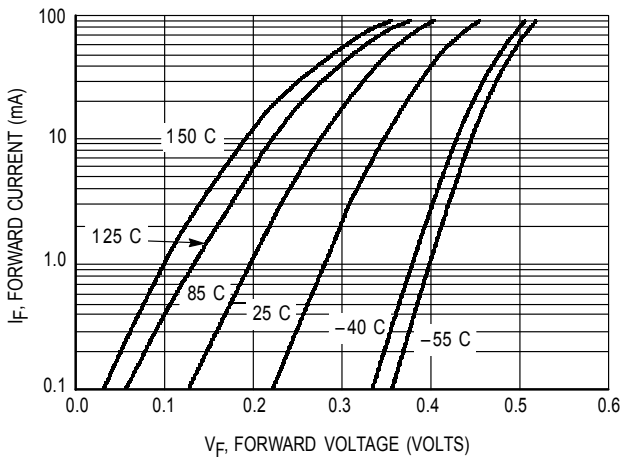


Figure 2. Forward Voltage

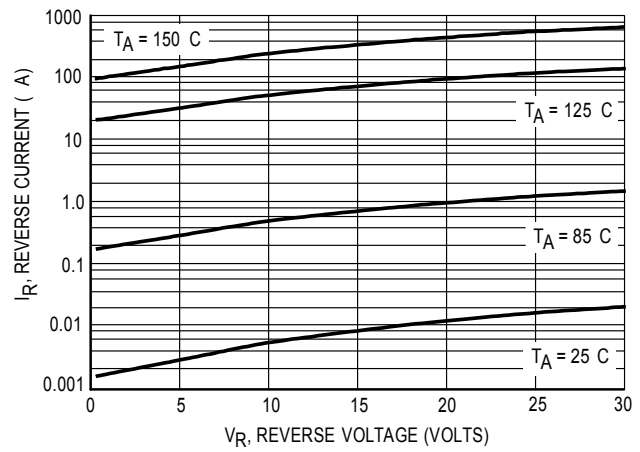


Figure 3. Leakage Current

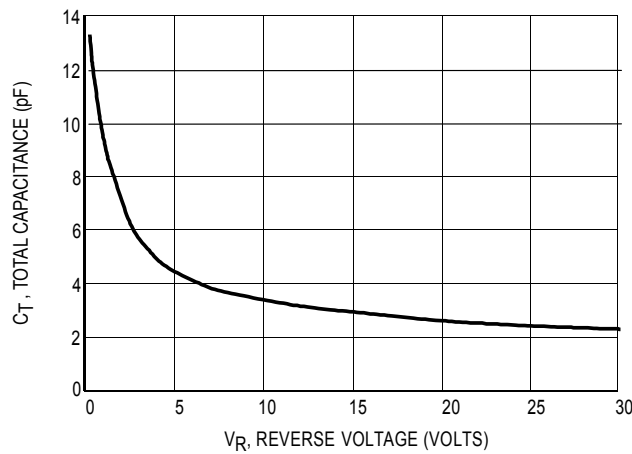
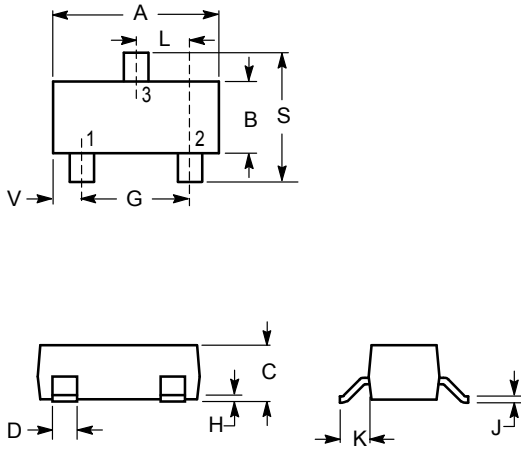


Figure 4. Total Capacitance

BAT54C

SOT-23



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

- PIN 1. ANODE
 2. ANODE
 3. CATHODE

